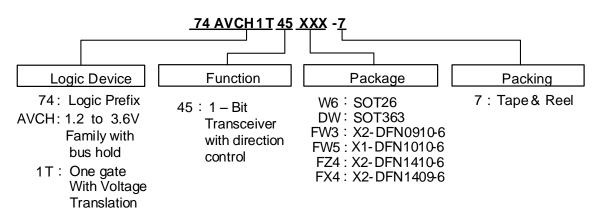


Ordering Information



Don't Name have	Backers Cade	Deelsening	7" Tape and Reel (Note 7)					
Part Number	Package Code	Packaging	Quantity	Part Number Suffix				
74AVCH1T45W6-7	W6	SOT26	3,000/Tape & Reel	-7				
74AVCH1T45DW-7	DW	SOT363	3,000/Tape & Reel	-7				
74AVCH1T45FW3-7	FW3	X2-DFN0910-6	5,000/Tape & Reel	-7				
74AVCH1T45FW5-7	FW5	X1-DFN1010-6	5,000/Tape & Reel	-7				
74AVCH1T45FZ4-7	FZ4	X2-DFN1410-6	5,000/Tape & Reel	-7				
74AVCH1T45FX4-7	FX4	X2-DFN1409-6	5,000/Tape & Reel	-7				

Notes: 4. The taping orientation is located on our website at http://www.diodes.com/datasheets/ap02007.pdf

Pin Descriptions

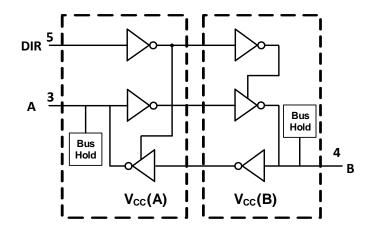
Pin Name	Pin	Function
VCC(A)	1	Supply for I/O pin A and reference for DIR
GND	2	Ground
Α	3	Data Input/Output
В	4	Data Input/Output
DIR	5	Direction Control
VCC(B)	6	Supply for I/O pin B

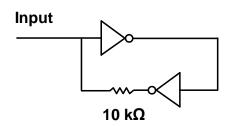
Function Table

Supply voltage	Input	Input/Output			
V _{CC(A)} , V _{CC(B)}	DIR (Direction Pin)	Α	В		
1.2 V to 3. 6 V	L	A=B	input		
1.2 V to 3. 6 V	Н	input	B=A		
GND	Х	Z	Z		



Logic Diagram





Bus Hold Circuit

Previous Input is Latched Input Signals must be strong enough to override 10kΩ

Absolute Maximum Ratings (Note 5) (@TA = +25°C, unless otherwise specified.)

Symbol	Parameter		Rating	Unit			
ESD HBM	Human Body Model ESD Protection		2	kV			
ESD CDM	Charged Device Model ESD Protection		1	kV			
ESD MM	Machine Model ESD Protection		200	V			
Vcc(A), Vcc(B)	Supply Voltage Range	upply Voltage Range					
VI	Input Voltage Range	-0.5 to +4.6	V				
Vo	Voltage Applied to Output in High Impedance or IOFF	-0.5 to +4.6	V				
	Voltage Applied to Output in High or Low State	A pin	-0.5 to V _{CC} (A) +0.5	V			
Vo	Voltage Applied to Output in High or Low State	B pin	-0.5 to V _{CC} (B) +0.5	V			
I _{IK}	Input Clamp Current V _I <0		-50	mA			
lok	Output Clamp Current		-50	mA			
lo	Continuous Output Current		±50	mA			
	Continuous Current Through V _{CC} or GND	±100	mA				
TJ	Operating Junction Temperature	-40 to +150	°C				
T _{STG}	Storage Temperature		-65 to +150	°C			

Note:

5. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.



Recommended Operating Condition (Notes 6, 7 & 8) (@T_A = +25°C, unless otherwise specified.)

Symbol	Para	meter	V _{CCI}	V _{cco}	Min	Max	Units
V _{CC} (A)	Operating Volta	ige	_	_	1.2	3.6	٧
V _{CC} (B)	Operating Volta	ge		_	1.2	3.6	V
			1.2 to 1.95V	1.2 to 3.6V	0.65 x V _{CC(A)}	_	
V _{IH}	High-Level Input Voltage	Data Inputs	1.95 to 2.7V	1.2 to 3.6V	1.6		V
	mpat voltage		2.7V to 3.6V	1.2 to 3.6V	2	_	
			1.2 to 1.95V	1.2 to 3.6V	_	0.35 x V _{CC(A)}	
VIL	Low-Level Input Voltage	Data Inputs	1.95 to 2.7V	1.2 to 3.6V	_	0.7	V
	input voltago		2.7V to 3.6V	1.2 to 3.6V	_	0.8	
		DIR	1.2 to 1.95V	1.2 to 3.6V	0.65 x V _{CC(B)}	1	
V _{IH}	High-Level Input Voltage	(referenced to	1.95 to 2.7V	1.2 to 3.6V	1.6		V
	par romago	V _{CCA})	2.7 to 3.6V	1.2 to 3.6V	2	-	
		DIR	1.2 to 1.95V	1.2 to 3.6V	_	0.35 x V _{CC(B)}	
VIL	V _{IL} Low-Level Input Voltage	(referenced to	1.95 to 2.7V	1.2 to 3.6V	_	0.7	٧
		Vcca)	2.7 to 3.6V	1.2 to 3.6V	_	0.8	
Vı	Input Voltage		_	_	0	3.6	V
W	Outrot Valtage	Active state	_	_	0	Vcco	V
Vo	Output Voltage	3-state	_	_	0	3.6	V
			1.2 to 3.6V	1.2V	_	-3	
			1.2 to 3.6V	1.4 to 1.6V		-6	
Іон	High-Level Out	out Current	1.2 to 3.6V	1.65 to 1.95V		-8	mA
			1.2 to 3.6V	2.3 to 2.7V	_	-9	
			1.2 to 3.6V	3 to 3.6V	_	-12	
			1.2 to 3.6V	1.2V	_	3	
			1.2 to 3.6V	1.4 to 1.6V	_	6	
loL	Low-Level Outp	out Current	1.2 to 3.6V	1.65 to 1.95V	_	8	mA
	Zon Zovor Garpar Garrons	1.2 to 3.6V	2.3 to 2.7V	_	9		
			1.2 to 3.6V	3 to 3.6V	_	12	
Δt/ΔV	Input Transition Rise or Fall Rate		1.2 to 3.6V 1.2 to 3.6V		_	5	ns/V
T _A	Operating Free	-Air Temperature			-40	+85	°C

Note:

- 6. VCCO is the VCC associated with the output port.
- 7. V_{CCI} is the V_{CC} associated with the input port.
- 8. All unused inputs of the device must be held at $V_{\mbox{CCI}}$ of GND.



Electrical Characteristics (Notes 9 & 10) (@T_A = +40°C to +85°C, unless otherwise specified.)

		_	10 1111	V (A)	V (D)	Т	_A = +25°	С	T _A = -40°C	to +85°C		
Symbol	Parameter	I	est Conditions	V _{CC} (A)	V _{CC} (B)	Min	Тур	Max	Min	Max	Unit	
		I _{OH} = -1	00μΑ	1.2 to 3.6V	1.2V to 3.6V	_	_	_	V _{CC} - 0.2	_		
		I _{OH} = -3	BmA	1.2V	1.2V	_	0.95	ı	_			
\/	High Level	I _{OH} = -6	6mA	1.4V	1.4V	_	_	l	1.05	_	V	
V _{OH}	Output Voltage	I _{OH} = -8	BmA	1.65V	1.65V	_	_		1.2	_	V	
		I _{OH} = -9	mA	2.3V	2.3V	_	_	-	1.75	_		
		I _{OH} = -1	2mA	3V	3V	_	_	_	2.3	_		
		I _{OL} = 100μA		1.2 to 3.6V	1.2V to 3.6V	_	_	-	_	0.2		
		$I_{OL} = 3r$	mA	1.2V	1.2V	_	0.15	_	_	_		
V _{OL}	Low-Level Output	$I_{OL} = 6r$	mA	1.4V	1.4V	_	_	_	_	0.35	V	
VOL	Voltage	$I_{OL} = 8r$	mA	1.65V	1.65V	_	_	-	_	0.45	V	
		$I_{OL} = 9r$	mA	2.3V	2.3V	_	—	_	_	0.55		
		I _{OL} = 12	2mA	3V	3V	_	_	_	_	0.7		
lı	Input Current	DIR	$V_I = V_{CC}(A)$ or GND	1.2 to 3.6V	1.2 to 3.6V	-0.25	±0.25	0.25	-1	1	μΑ	
I _{OFF}	Power Down	A Pin	V_1 or $V_0 = 0$ to 3.6V	0V	0 to 3.6V	-1	±0.1	1	-5	5	μA	
-	Leakage Current	B Pin		0 to 3.6V	0	-1	±0.1	1	-5	5	·	
	3-State Leakage	B Pin	$V_O = V_{CCO}$ or Gnd	0V	0 to 3.6V	-2.5	±0.5	2.5	-5	5		
loz	Current	A Pin	V _I = V _{CCI} or Gnd	0 to 3.6V	0	-2.5	±0.5	2.5	-5	5	μA	
		., .,	2115	1.2 to 3.6V	11.2 to 3.6V	_	_	-	_	10		
I _{CCA}	Supply Current	-	CI or GND	3.6V	0V	_	_		_	-2	μA	
		$I_0 = 0$		0V	3.6V	_	_	_	_	10		
		., .,	· · OND	1.2 to 3.6V	1.2 to 3.6V	_	_	_	_	10		
I _{CCB}	Supply Current	_	CI or GND	0V	3.6V	_	_	1	_	10	μΑ	
		$I_0 = 0$		3.6V	0V	_	_	_	_	-2		
I _{CCA} +	Supply Current	$V_I = V_{CCI}$ or GND $I_O = 0$		1.2 to 3.6V	1.2 to 3.6V	_	_	-	_	20	μΑ	
Cı	Input Capacitance	DIR $V_{I}=V_{CC}(A)$ or GND		3.3V	3.3V	_	2.5		_	_	pF	
Cio	Input/Output Capacitance	A or B pin	$V_I = V_{CC}(A)/(B)$ or GND	3.3V	3.3V	_	6.0	_	_	_	pF	

Notes:

^{9.} $\mbox{V}_{\mbox{CCO}}$ is the $\mbox{V}_{\mbox{CC}}$ associated with the output port.

^{10.} V_{CCI} is the V_{CC} associated with the input port.



Package Characteristics ($V_{CC} = 3.3V$, $T_A = +25$ °C, unless otherwise specified.)

Symbol	Parameter	Package	Test Conditions	Min	Тур	Max	Unit	
		SOT26		_	166	_		
		SOT363	(Nation 44)	_	371	_		
_	Thermal Resistance Junction-	X2-DFN0910-6		_	530	1	°C/W	
θ_{JA}	to-Ambient	X2- DFN1410-6	(Note 11)	_	430	_	*C/VV	
		X2-DFN1409-6		_	450	_		
		X1-DFN1010-6		_	510	_		
		SOT26		_	46	1		
		SOT363		_	143	1		
0	Thermal Resistance Junction-	X2-DFN0910-6	(Note 11)	_	260	_	°C/W	
$\theta_{ m JC}$	to-Case	X2- DFN1410-6	(Note 11)	_	190	_	C/VV	
		X2-DFN1409-6		_	200	1		
		X1-DFN1010-6		_	250	_		

Note:

Switching Characteristics

 V_{CC} (A) = 1.2V, T_A = -40°C to +85°C, See Figure 1

Parameter	From (Input)	To (Output)	V _{CC} (B) = 1.2V	V _{CC} (B) = 1.5V ±0.1	V _{CC} (B) = 1.8V ±0.15V	V _{CC} (B) = 2.5V ±0.2V	V _{CC} (B) = 3.3V ±0.3V	Unit							
	(iliput)	(Output)	TYP	TYP	TYP	TYP	TYP								
t _{PLH}	Α	В	3.3	2.7	2.4	2.3	2.4	ns							
t _{PHL}	A	Ь	3.3	2.7	2.4	2.3	2.4	115							
t _{PLH}	В	Α	3.3	3.1	2.9	2.8	2.7	ns							
t _{PHL}	ь	A	3.3	3.1	2.9	2.8	2.7	115							
t _{PHZ}	DIR	Α	5.1	5.2	5.3	5.2	3.7	ns							
t_{PLZ}	DIK	A	5.1	5.2	5.3	5.2	3.7	115							
t_{PHZ}	DIR	В	5.3	4.3	4.0	3.3	3.7	ns							
t _{PLZ}	DIK	ь	5.3	4.3	4.0	3.3	3.7	115							
t _{PZH} *	DIR	Α	8.6	7.3	6.8	6.1	6.4	ns							
t _{PZL} *	DIK	A	8.6	7.3	6.8	6.1	6.4	115							
t _{PZH} *	DIR	D	8.3	7.8	7.7	7.5	5.8	ns							
t _{PZL} *	אוט	В	В	В	В	В	В	В	В	8.3	7.8	7.7	7.5	5.8	1115

^{*}Enable times are calculated vales see table at end of switching characteristics.

V_{CC} (A) = 1.5V \pm 0.1V, T_A = -40°C to +85°C, See Figure 1

Parameter	From	To (Output)	V _{CC} (B) = 1.2V			V _{CC} (B) = 1.8V ±0.15V		V _{CC} (B) = 2.5V ±0.2V		V _{CC} (B) = 3.3V ±0.3V		Unit		
	(Input)	(Output)	TYP	Min	Max	Min	Max	Min	Max	Min	Max			
t _{PLH}	Α	В	2.9	0.7	5.6	0.6	5.2	0.5	4.2	0.5	3.8	ns		
t _{PHL}	A	Б	2.9	0.7	5.6	0.6	5.2	0.5	4.2	0.5	3.8	115		
t _{PLH}	В	Α	2.6	0.6	5.5	0.4	5.3	0.3	4.9	0.3	4.8	ns		
t _{PHL}	Ь	A	2.6	0.6	5.5	0.4	5.3	0.3	4.9	0.3	4.8	115		
t_{PHZ}	DIR	Α	3.8	1.6	6.7	1.5	6.8	0.3	6.9	0.9	6.9	ns		
t_{PLZ}	DIK	ζ.	3.8	1.6	6.7	1.5	6.8	0.3	6.9	0.9	6.9	115		
t _{PHZ}	DID	В	5.1	1.8	8.1	1.6	7.1	1.1	4.7	1.4	4.5	ns		
t _{PLZ}	DIR	DIR	В	5.1	1.8	8.1	1.6	7.1	1.1	4.7	1.4	4.5	115	
t _{PZH} *	DID	^	7.7	_	13.6	1	12.4	_	9.6		9.3	ns		
t _{PZL} *	DIR	DIR A	7.7	_	13.6	1	12.4	_	9.6		9.3	115		
t _{PZH} *	DID	JIP B	6.7	_	12.3		12	_	11.1	1	10.7	ns		
t _{PZL} *	DIR	DIR	В	В	6.7	_	12.3		12	_	11.1		10.7	115

^{*}Enable times are calculated vales see table at end of switching characteristics.

^{11.} Test condition for all packages: Device mounted on FR-4 substrate PC board, 2oz copper with minimum recommended pad layout.



Switching Characteristics (Continued)

 V_{CC} (A) = 1.8V ± 0.15V, T_A = -40°C to +85°C, See Figure 1

Parameter	From (Input)	To (Output)	V _{CC} (B) = 1.2V		= 1.5V 0.1		= 1.8V 15V	V _{CC} (B) ±0	= 2.5V .2V		= 3.3V .3V	Unit	
	(iliput)	(Output)	(Output)	TYP	Min	Max	Min	Max	Min	Max	Min	Max	
t _{PLH}	Α	В	2.7	0.6	5.3	0.5	5.0	0.4	3.9	0.4	3.4	ns	
t _{PHL}		Ь	2.7	0.6	5.3	0.5	5.0	0.4	3.9	0.4	3.4	113	
tpLH	В	Α	2.3	0.5	5.2	0.4	5.0	0.3	4.6	0.2	4.4	ns	
t _{PHL}	Б	^	2.3	0.5	5.2	0.4	5.0	0.3	4.6	0.2	4.4	115	
t _{PHZ}	DIR	Α	3.8	1.6	5.9	1.6	5.9	1.6	5.9	0.5	6.0	ns	
t _{PLZ}	DIK	^	3.8	1.6	5.9	1.6	5.9	1.6	5.9	0.5	6.0	115	
t _{PHZ}	DIR	В	5.0	1.8	7.7	1.4	6.8	1.0	4.4	1.4	5.3	ns	
t_{PLZ}	DIK	В	5.0	1.8	7.7	1.4	6.8	1.0	4.4	1.4	5.3	115	
t _{PZH} *	DIR	_	7.3	_	12.9		11.8		9.0		8.7	ns	
t _{PZL} *	DIK	OIR A	7.3	_	12.9		11.8		9.0	_	8.7	115	
t _{PZH} *	DID	В	6.5	_	11.2	_	10.9	_	9.8	_	9.4	nc	
t _{PZL} *	DIR	В	6.5	_	11.2	_	10.9	_	9.8	_	9.4	ns	

^{*}Enable times are calculated vales see table at end of switching characteristics.

V_{CC} (A) = 2.5V \pm 0.2V, T_A = -40°C to +85°C, See Figure 1

Parameter	From (Input)	To (Output)	V _{CC} (B) = 1.2V		= 1.5V 0.1		= 1.8V 15V	V _{CC} (B) ±0	= 2.5V .2V		= 3.3V .3V	Unit																																							
	(iliput)	(Output)	TYP	Min	Max	Min	Max	Min	Max	Min	Max																																								
t _{PLH}	Α	В	2.6	0.5	4.9	0.4	4.6	0.3	3.4	0.3	3.0	200																																							
t _{PHL}	A	Ь	2.6	0.5	4.9	0.4	4.6	0.3	3.4	0.3	3.0	ns																																							
t _{PLH}	В	А	2.2	0.4	4.2	0.3	3.8	0.2	3.4	0.2	3.3	200																																							
t _{PHL}		_ ^	2.2	0.4	4.2	0.3	3.8	0.2	3.4	0.2	3.3	ns																																							
t _{PHZ}	DIR	А	2.8	0.3	3.8	0.8	3.8	0.4	3.8	0.5	3.8	200																																							
t _{PLZ}	DIK	ζ.	2.8	0.3	3.8	0.8	3.8	0.4	3.8	0.5	3.8	ns																																							
t _{PHZ}	DIR	В	4.9	2.0	7.6	1.5	6.5	0.6	4.1	1.0	4.0	200																																							
t _{PLZ}	DIK	Ь	4.9	2.0	7.6	1.5	6.5	0.6	4.1	1.0	4.0	ns																																							
t _{PZH} *	DIR	_	7.1	_	11.8	_	10.3	_	7.5	_	7.3	20																																							
t _{PZL} *	DIK	A	Α	A	A	A	A	A	А	А	А	A	A	A	А	А	A	A	A	A	A	Α	Α	A	A	A	A	A	A	A	A	A	A	A	A	A	A	Α -	A	A	A	7.1	_	11.8	_	10.3	_	7.5	_	7.3	ns
t _{PZH} *	DIB	D	5.4	_	8.6	-	8.1	_	7.0	_	6.6	200																																							
t _{PZL} *	אוט	В	В	В	В	В	В	В	В	В	В	В	В	В	DIR B	5.4	_	8.6	_	8.1	_	7.0	_	6.6	ns																										

^{*}Enable times are calculated vales see table at end of switching characteristics.

V_{CC} (A) = 3.3V \pm 0.3V, T_A = -40°C to +85°C, See Figure 1

Parameter	From (Input)	To (Output)	V _{CC} (B) = 1.2V		= 1.5V 0.1		= 1.8V 15V	V _{CC} (B)	= 2.5V .2V		= 3.3V .3V	Unit					
	(iliput)	(Output)	TYP	Min	Max	Min	Max	Min	Max	Min	Max						
t _{PLH}	Α	В	2.6	0.4	4.7	0.3	4.4	0.2	3.3	0.2	2.8						
t _{PHL}	A	Ь	2.6	0.4	4.7	0.3	4.4	0.2	3.3	0.2	2.8	ns					
t _{PLH}	В	^	2.2	0.4	3.8	0.3	3.4	0.2	3	0.1	2.8	20					
t _{PHL}	В	Α	А	A	A	A	Α.	2.2	0.4	3.8	0.3	3.4	0.2	3	0.1	2.8	ns
t _{PHZ}	DIR	Α	3.1	1.3	4.3	1.3	4.3	1.3	4.3	1.3	4.3	20					
t _{PLZ}	אוט	A	3.1	1.3	4.3	1.3	4.3	1.3	4.3	1.3	4.3	ns					
t _{PHZ}	DIR	В	4	0.7	7.4	0.6	6.5	0.7	4	1.5	4.9						
t _{PLZ}	אוט	Ь	4	0.7	7.4	0.6	6.5	0.7	4	1.5	4.9	ns					
t _{PZH} *	DID	^	6.2	_	11.2	_	9.9	_	7	_	6.7	20					
t _{PZL} *	אוט	RA	A	Α -	IR A	6.2	_	11.2	_	9.9	_	7	_	6.7	ns		
t _{PZH} *	DIR	В	5.7	_	8.9	_	8.5	_	7.2	_	6.8	20					
t _{PZL} *	אוט	В	5.7	_	8.9	_	8.5	_	7.2	_	6.8	ns					

^{*}Enable times are calculated vales see table at end of switching characteristics.



Enable Time Calculations

Enable times can be calculated as follows:

- t_{PZH} (DIR to A) = t_{PLZ} (DIR to B) + t_{PLH} (B to A)
- t_{PZL} (DIR to A) = t_{PHZ} (DIR to B) + t_{PHL} (B to A)
- t_{PZH} (DIR to B) = t_{PLZ} (DIR to A) + t_{PLH} (A to B)
- t_{PZL} (DIR to B) = t_{PHZ} (DIR to A) + t_{PHL} (A to B)

These times represent the length of time from a direction change plus the propagation time through the part.

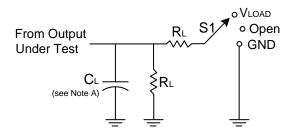
A new input signal should not be applied until the new input pin has been disabled.

Operating Characteristics (T_A = +25°C, unless otherwise specified.)

Parameter Power Dissipation Capacitance		Test Conditions	$V_{CC}(A) = V_{CC}(B) = 1.8V$	$V_{CC}(A) = V_{CC}(B) = 2.5V$	$V_{CC}(A) = V_{CC}(B) = 3.3V$	$V_{CC}(A) = V_{CC}(B) = 5V$	Unit
			Тур	Тур	Тур	Тур	
	A- input, B- output	$C_L = 0 pF$	3	4	4	4	
C _{PD} (A)	B- input, A- output	f = 10 MHz tr = tf = 1 ns	18	19	20	21	pF
	A- input, B- output	$C_L = 0 pF$	18	19	20	21	
C _{PD} (B)	B- input, A- output	f = 10 MHz tr = tf = 1 ns	3	4	4	4	pF

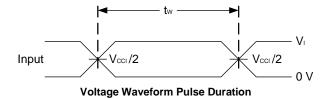


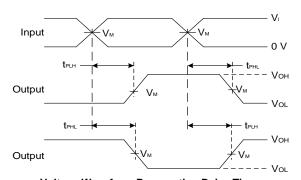
Parameter Measurement Information



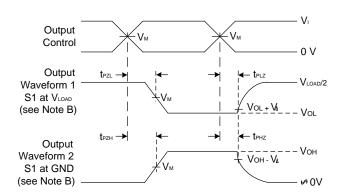
TEST	S1
t _{PLH} /t _{PHL}	Open
t _{PLZ} /t _{PZL}	Vload
t _{PHZ} /t _{PZH}	GND

V	Inputs		V V	V	CL	RL	V Δ
V _{CC}	VI	t _R /t _F	V _M V _{LOAD}				
1.2V	Vccı	≤2ns	V _{CCO} /2	2 x V _{CCO}	15pF	2ΚΩ	0.15V
1.8V±0.15V	V _{CCI}	≤2ns	V _{CCO} /2	2 x V _{CCO}	15pF	2ΚΩ	0.15V
2.5V±0.2V	Vccı	≤2ns	V _{CCO} /2	2 x V _{CCO}	15pF	2ΚΩ	0.15V
3.3V±0.3V	V _{CCI}	≤2.5ns	V _{CCO} /2	2 x V _{CCO}	15pF	2ΚΩ	0.3V





Voltage Waveform Propagation Delay Times Inverting and Non Inverting Outputs



Voltage Waveform Enable and Disable Times Low and High Level Enabling

Figure 1 Load Circuit and Voltage Waveforms

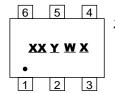
Notes: A. Includes test lead and test apparatus capacitance.

- B. Waveform 1 is for an output with input set up as a low and device coming out or into 3-state via DIR control. Waveform 2 is for an output with input set up as a high and device coming out or into 3-state via DIR control.
- C. All pulses are supplied at pulse repetition rate ≤ 10 MHz.
- D. t_{PLZ} and t_{PHZ} are the same as t_{DIS}.
- E. t_{PZL} and t_{PZH} are the same as t_{EN}.
- F. t_{PLH} and t_{PHL} are the same as $t_{PD.}$
- G. V_{CCI} is the V_{CC} associated with the input.
- F. V_{CCO} is the V_{CC} associated with the output.



Marking Information

(1) SOT26, SOT363



XX : Identification code Y : Year 0~9

<u>W</u>: Week: A~Z: 1~26 week;

a~z : 27~52 week; z represents 52 and 53 week

 \underline{X} : A~Z: Internal Code

Part Number	Package	Identification Code
74AVCH1T45W6-7	SOT26	VT
74AVCH1T45DW-7	SOT363	VR

(2) X2-DFN0910-6, X2-DFN1010-6, X2-DFN1410-6, and X2-DFN1409-6

(Top View)

XΧ

XX: I dentification Code Y: Year: 0~9 W: Week: A~Z: 1~26 week; a~z: 27~52 week; z represents 52 and 53 week X: A~Z: Interpretended

X: A~Z: Internal code

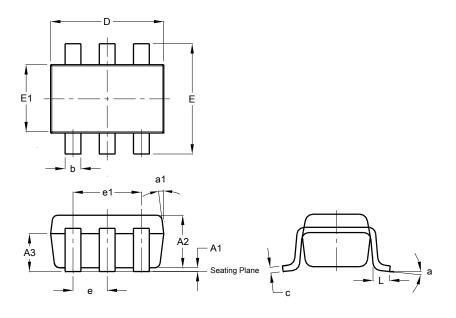
Part Number	Package	Identification Code
74AVCH1T45FW3-7	X2-DFN0910-6	ZR
74AVCH1T45FW5-7	X1-DFN1010-6	VR
74AVCH1T45FX4-7	X2-DFN1409-6	VT
74AVCH1T45FZ4-7	X2-DFN1410-6	VS



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT26

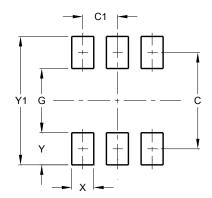


	SOT26					
Dim	Min	Max	Тур			
A1	0.013	0.10	0.05			
A2	1.00	1.30	1.10			
А3	0.70	0.80	0.75			
b	0.35	0.50	0.38			
С	0.10	0.20	0.15			
D	2.90	3.10	3.00			
е	-	-	0.95			
e1	-	-	1.90			
Е	2.70	3.00	2.80			
E1	1.50	1.70	1.60			
L	0.35	0.55	0.40			
а	-	-	8°			
a1	-	-	7°			
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT26



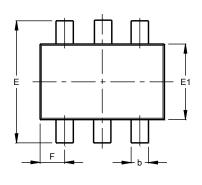
Dimensions	Value (in mm)
С	2.40
C1	0.95
G	1.60
Х	0.55
Υ	0.80
Y1	3.20

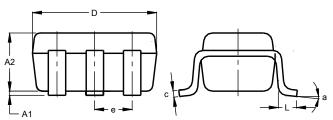


Package Outline Dimensions (Cont.)

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT363



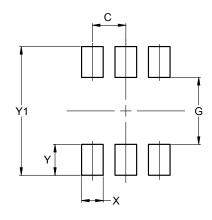


	SOT363					
Dim	Min	Max	Тур			
A1	0.00	0.10	0.05			
A2	0.90	1.00	1.00			
b	0.10	0.30	0.25			
С	0.10	0.22	0.11			
D	1.80	2.20	2.15			
Е	2.00	2.20	2.10			
E1	1.15	1.35	1.30			
е	C).650 E	SC			
F	0.40	0.45	0.425			
L	0.25	0.40	0.30			
а	0°	8°				
All	All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT363



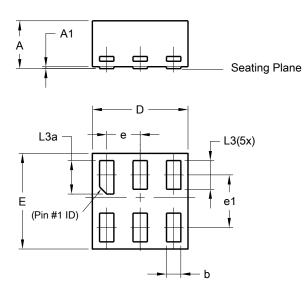
Dimensions	Value (in mm)
С	0.650
G	1.300
X	0.420
Υ	0.600
Y1	2.500



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

X1-DFN1010-6 (Type B)

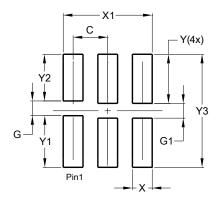


X1-DFN1010-6 (Type B)				
Dim	Dim Min Max Typ			
Α	-	0.50	0.39	
A1	-	0.04	-	
b	0.12	0.20	0.15	
D	0.95	1.050	1.00	
Е	0.95	1.050	1.00	
е	0.35 BSC			
e1		0.55 B	SC	
L3	0.27	0.30	0.30	
L3a	0.32	0.40	0.35	
All	Dimen	sions i	in mm	

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

X1-DFN1010-6 (Type B)



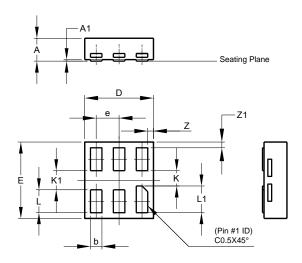
Dimensions	Value (in mm)
	,
С	0.350
G	0.150
G1	0.150
Х	0.200
X1	0.900
Υ	0.500
Y1	0.525
Y2	0.475
Y3	1.150



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

X2-DFN0910-6

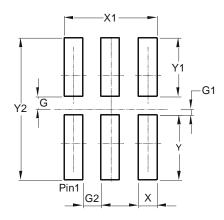


)	X2-DFN0910-6					
Dim	Min	Max	Тур			
Α	-	0.35	0.30			
A1	0	0.03	0.02			
b	0.10	0.20	0.15			
D	0.85	0.95	0.90			
Е	0.95	1.05	1.00			
е	-	-	0.30			
K	0.20	-	-			
K 1	0.25	-	-			
L	0.25	0.35	0.30			
L1	0.30	0.40	0.35			
Z	-	-	0.075			
Z 1	-	-	0.075			
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

X2-DFN0910-6



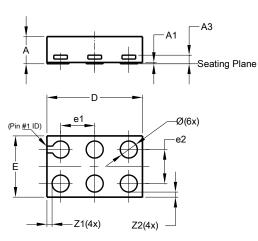
Dimensions	Value	
Dillielisions	(in mm)	
G	0.100	
G1	0.050	
G2	0.150	
Х	0.150	
X1	0.750	
Υ	0.525	
Y1	0.475	
Y2	1.150	



Package Outline Dimensions (Cont.)

Please see http://www.diodes.com/package-outlines.html for the latest version.

X2-DFN1409-6

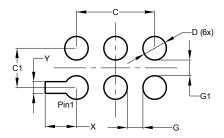


X2-DFN1409-6				
Dim	Min	Max	Тур	
Α	-	0.40	0.39	
A1	0	0.05	0.02	
А3	-	-	0.13	
Ø	0.20	0.30	0.25	
D	1.35	1.45	1.40	
Е	0.85	0.95	0.90	
e1	-	-	0.50	
e2	-	-	0.50	
Z1	-	-	0.075	
Z2	-	-	0.075	
All Dimensions in mm				

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

X2-DFN1409-6

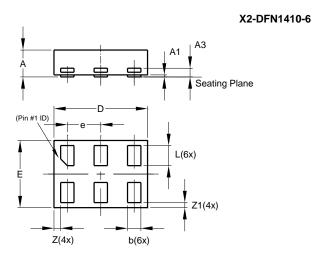


Dimensions	Value	
Dillicitations	(in mm)	
С	1.000	
C1	0.500	
D	0.300	
G	0.200	
G1	0.200	
Х	0.400	
Y	0.150	



Package Outline Dimensions (Cont.)

Please see http://www.diodes.com/package-outlines.html for the latest version.

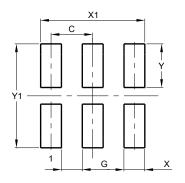


X2-DFN1410-6			
Dim	Min	Max	Тур
Α	_	0.40	0.39
A1	0.00	0.05	0.02
A3	_	_	0.13
b	0.15	0.25	0.20
D	1.35	1.45	1.40
E	0.95	1.05	1.00
е			0.50
L	0.25	0.35	0.30
Z			0.10
Z 1	0.045	0.105	0.075
All Dimensions in mm			

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

X2-DFN1410-6



Dimensions	Value (in mm)
С	0.500
G	0.250
Х	0.250
X1	1.250
Y	0.525
Y1	1.250



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